NSN 5961-01-340-1357

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View Online at https://aerobasegroup.com/nsn/5961-01-340-1357 **Inclosure Material:** Metal and ceramic **Overall Length:** Between 0.890 inches and 0.910 inches **Overall Height:** Between 0.200 inches and 0.230 inches Overall Width: 0.830 inches **End Application:** Radar set an/sps-40d **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Slot **Features Provided:** Gold plated leads and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 25.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter **Current Rating Per Characteristic:** 5.40 amperes source cutoff current **Power Rating Per Characteristic:** 87.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 flange and 2 ribbon Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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